A particle-in-cell/Monte Carlo simulation of a capacitively coupled chlorine discharge

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Introduction

- Chlorine is an electronegative diatomic gas that is widely used in plasma etching of both semiconductors and metals, in particular poly-silicon gate and aluminum interconnects
- Chlorine atoms are believed to be the primary reactant in plasma etching
- The chlorine molecule has
 - a low dissociation energy (2.5 eV)
 - lacktriangledown a near-zero threshold energy for dissociative attachment
- All electronic excitations of the molecule appear to be dissociative, and no metastable molecular states are of importance

Outline

- The 1D particle-in-cell/Monte Carlo collision simulation
 - The chlorine discharge
- Comparison with measurements
- Capacitively Coupled Chlorine Discharge at 13.56 MHz Voltage Source
- Capacitively Coupled Chlorine Discharge at 27.12 MHz Current Source
- Capacitively Coupled Chlorine Discharge dual frequency 27.12 MHz and 2 MHz Current Source
- Summary

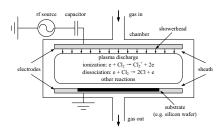
The 1D particle-in-cell/Monte Carlo collision simulation

The oopd1 1d-3v PIC/MCC code

- We use the oopd1 (objective oriented plasma device for one dimension) code to simulate the discharge
- The oopd1 code was originally developed at the Plasma Theory and Simulation Group at UC Berkeley
- It has 1 dimension in space and 3 velocity components for particles (1d-3v)
- The oopd1 code is supposed to replace the widely used xpdx1 series (xpdp1, xpdc1 and xpds1)
- It is developed to simulate various types of plasmas, including processing discharges, accelerators and beams
 - Modular structure
 - Includes relativistic kinematics
 - Particles can have different weights



The chlorine discharge



- We consider a discharge that consists of:
 - electrons
 - \blacksquare the ground state chlorine molecule $\text{\rm Cl}_2(X\,{}^1\Sigma_g^+,\,\nu=0),$
 - the ground state chlorine atom Cl(3p^{5 2}P)
 - the negative chlorine ion CI[−]
 - the positive chlorine ions Cl⁺ and Cl⁺₂



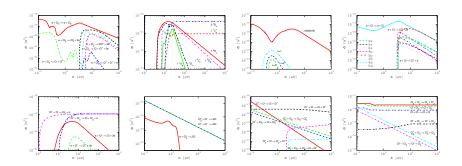
The chlorine discharge

- In the chlorine discharge, the number of Cl atoms is much larger than the number of charged species
- Thus, we apply a global model¹ beforehand to calculate the fraction of Cl atoms under certain control parameters including the discharge pressure, absorbed power and the gap length between two electrodes
- The absorbed power found in the PIC/MCC simulation is used as an input parameter in the global model iteratively
- Both Cl₂ molecules and Cl atoms are treated as the initial background gas in the simulation



¹ Thorsteinsson and Gudmundsson, Plasma Sources Sci. Technol., 19 015001 (2010)

The chlorine discharge



■ The reaction set for the chlorine is comprehensive and includes 44 reactions

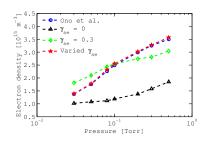
Huang and Gudmundsson, Plasma Sources Sci. Technol., 22 055020 (2013)



Comparison with experiments

Comparison with experiments

- Electron density versus discharge pressure (30 – 600 mTorr)
- Secondary electrons actually affect the electron density
- We allow the secondary electron emission coefficient, γ_{se} , to vary from 0.15 to 0.45 in order to fit the simulation to the experimental values

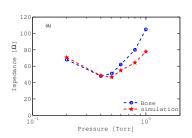


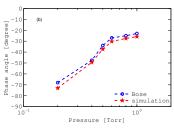
Ono et al., 1992, J. Vac. Sci. Technol. A, 10 1071

Comparison with experiments

- Impedance and phase angle versus discharge pressure
- Secondary electrons have little influence
- The agreement with the measured data is excellent with only small discrepancy above 600 mTorr in the impedance

Bose, PhD Thesis, Swiss Federal Institute of Technology Zurich, 1995

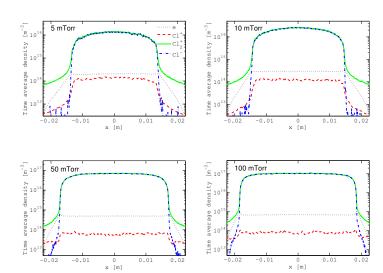




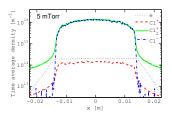
We apply a voltage source with a single frequency

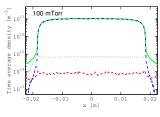
$$V(t) = V_{\rm rf} \sin(2\pi f t)$$

- The electrodes are circular with a diameter of 14.36 cm
- The gap between the electrodes is 4.5 cm
- We set V_{rf} = 222 V and f = 13.56 MHz
- The neutrals (Cl₂ and Cl) are treated as background gas at $T_g = 300 \text{ K}$ with a Maxwellian distribution
- The dissociation fraction is found using a global model
- The explored pressure range is 5 100 mTorr

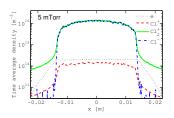


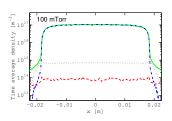
- At low pressures, the profile for Cl₂⁺ ions is cosine-like or parabolic since Cl₂⁺ ions are lost mainly due to diffusion to the walls
- As the pressure increases, the recombination between Cl₂⁺ and Cl⁻ ions becomes the major loss mechanism for Cl₂⁺ ions
- Thus, the density profile for Cl₂⁺ and Cl⁻-ions becomes quite flat in the bulk region



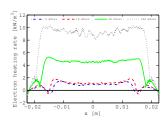


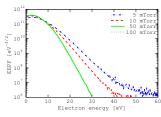
- The density profile for Cl⁺-ions is very different from that for Cl₂⁺-ions
- In the bulk region the density of Cl⁺-ions is uniform at relatively low value
- In the sheath region the density of Cl⁺-ions increases with increasing pressure – through non-resonant charge transfer





- At low pressures the power absorbed by the electrons is distributed in the bulk and sheath region through electron—neutral collisions and stochastic heating due to the oscillating sheath, respectively
- At high pressures the power absorbed by the electrons is mainly due to electron-neutral collisions in the bulk





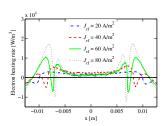
Capacitively Coupled Chlorine Discharge at 27.12 MHz – Current Source

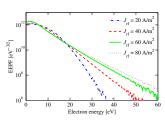
We apply a current source with a single frequency

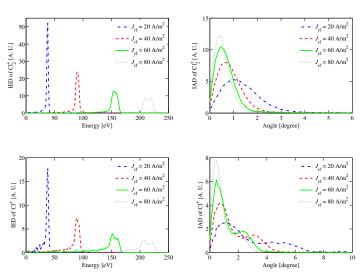
$$J(t) = J_{\rm rf} \sin(2\pi f t)$$

- The electrodes are circular with a diameter of 10.2 cm
- The gap between the electrodes is 2.54 cm
- We set $J_{rf} = 20 80 \text{ A/m}^2$ and f = 27.12 MHz
- The neutrals (Cl₂ and Cl) are treated as background gas at $T_g = 300 \text{ K}$ with a Maxwellian distribution
- The dissociation fraction is found using a global model
- The pressure is 10 mTorr

- Stochastic heating in the sheath becomes more prominent as the current increases
- The electron energy distribution function changes from Druyvesteyn to Maxwellian, and then to bi-Maxwellian as the current increases







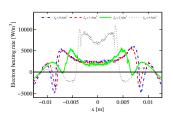
Capacitively Coupled Chlorine Discharge – dual frequency 27.12 MHz and 2 MHz – Current Source

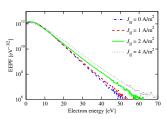
We apply a current source that consists of two frequency components

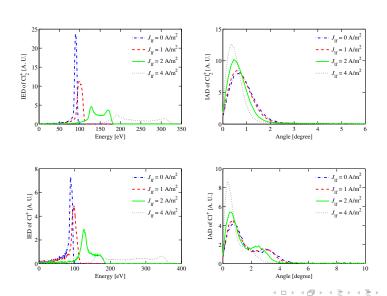
$$J(t) = J_{\rm hf} \sin(2\pi f_{\rm hf} t) + J_{\rm lf} \sin(2\pi f_{\rm lf} t)$$

- The electrodes are circular with a diameter of 10.2 cm
- The gap between the electrodes is 2.54 cm
- We set $J_{hf} = 40 \text{ A/m}^2$ and f = 27.12 MHz
- We set $J_{1f} = 1 4 \text{ A/m}^2$ and f = 2 MHz
- The neutrals (Cl₂ and Cl) are treated as background gas at $T_g = 300$ K with a Maxwellian distribution
- The dissociation fraction is found using a global model
- The pressure is 10 mTorr

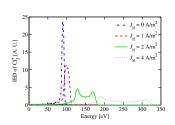
- As the low-frequency current increases, the heating in the bulk region first decreases slightly and then increases dramatically
- The number of low-energy electrons first increases and then decreases, while the number of the high-energy electrons increases steadily with increasing low frequency current

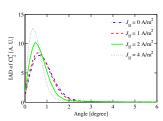




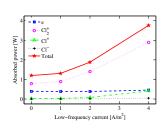


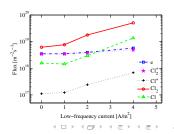
- The IED becomes wider and extends to the high-energy region with increasing low-frequency current
- The IAD is more concentrated in the small-angle region with increasing low-frequency current





- The average sheath potential drop increases with increased low frequency current and thus the absorbed power while the flux of charged particles remains roughly constant
- The flux of high energy (> 1 eV) neutrals and Cl⁺ increases with increased low frequency current





Summary

- We demonstrated particle-in-cell/Monte Carlo collision simulation of a capcacitively coupled chlorine disharge
- Both chlorine atoms and Cl⁺-ions are considered in the reaction set
- We explored voltage source driven discharge of single frequency and current source driven single and dual frequency discharges

References

The slides can be downloaded at

http://langmuir.raunvis.hi.is/~tumi/plasma.html

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- Gudmundsson, J. T., E. Kawamura, and M. A. Lieberman (2013). A benchmark study of a capacitively coupled oxygen discharge of the oopd1 particle-in-cell Monte Carlo code. *Plasma Sources Science and Technology* 22(3), 035011.
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- Ono, K., T. Oomori, M. Tuda, and K. Namba (1992). Measurements of the Cl atom concentration in radio-frequency and microwave plasmas by two-photon laser-induced fluorescence: Relation to the etching of Si. *Journal of Vacuum Science and Technology A* 10(4), 1071–1079.
- Thorsteinsson, E. G. and J. T. Gudmundsson (2010). A global (volume averaged) model of a chlorine discharge. Plasma Sources Science and Technology 19(1), 015001.